

## PWK2333

### 12V P-Channel MOSFET

-6A -12V;  $R_{DS(ON)typ}=19m\Omega@-4.5V$ ,  $R_{DS(ON)typ}=21m\Omega@-3.7V$ ,  
 $R_{DS(ON)typ}=27m\Omega@-2.5V$ ,  $R_{DS(ON)typ}=35m\Omega@-1.8V$ ,  
 $R_{DS(ON)typ}=50m\Omega@-1.5V$

#### FEATURE

- TrenchFET Power MOSFET
- Excellent  $R_{DS(on)}$  and Low Gate Charge

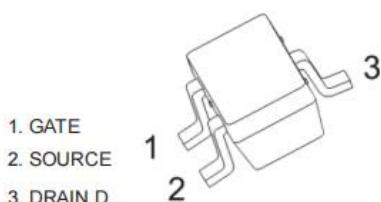
#### Application

- DC/DC Converter
- Load Switch for Portable Devices
- Battery Switch

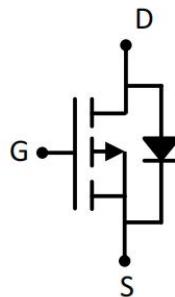
#### MARKING:



SOT-23-3L



Schematic diagram



#### ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-12	V
Gate-Source Voltage	$V_{GS}$	$\pm 8$	V
Continuous Drain Current <sup>(1,5)</sup>	$I_D$	-6	A
Pulsed Drain Current <sup>(2)</sup>	$I_{DM}$	-20	A
Power Dissipation <sup>(4,5)</sup>	$P_D$	1.7	W
Thermal Resistance from Junction to Ambient <sup>(5)</sup>	$R_{\theta JA}$	73.5	$^\circ C/W$
Junction and Storage Temperature	$T_J, T_{STG}$	-55~+150	$^\circ C$

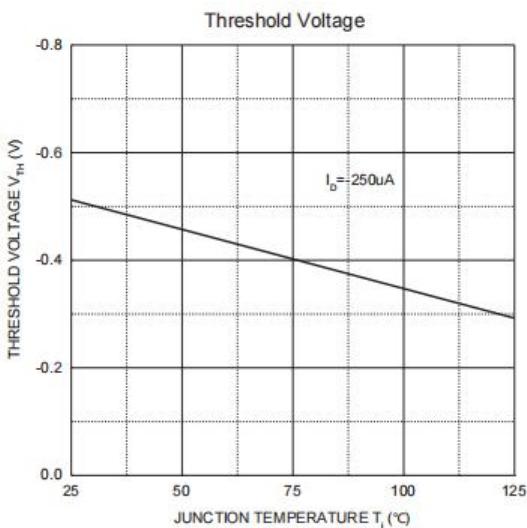
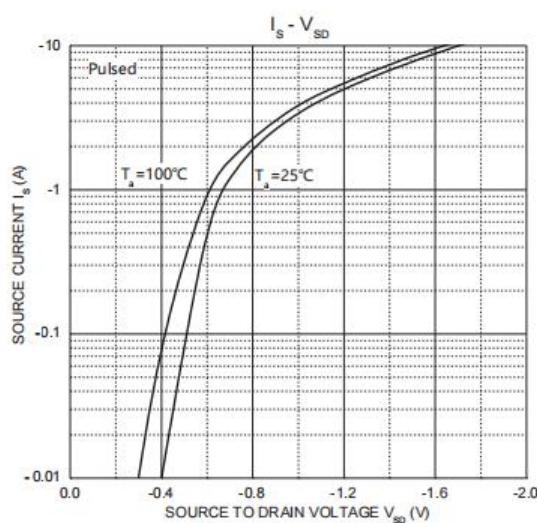
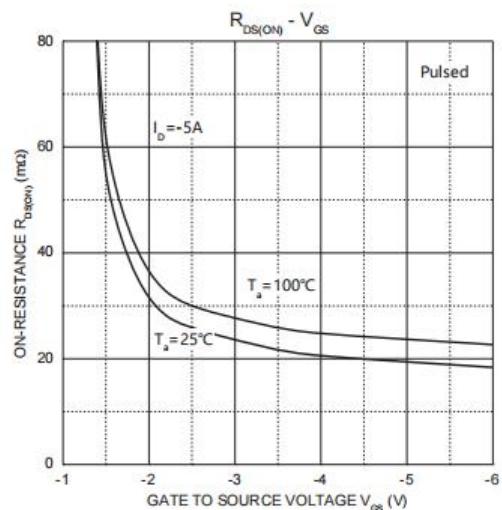
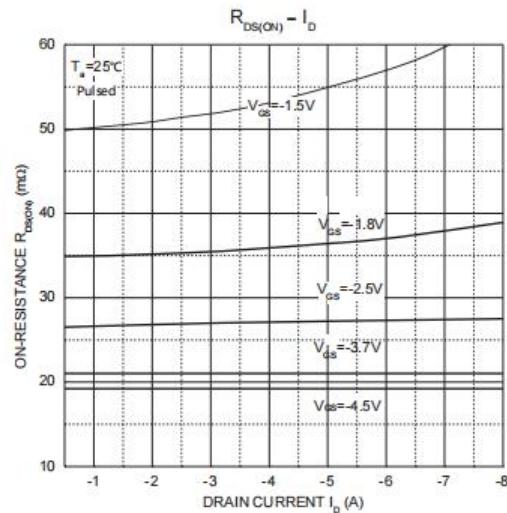
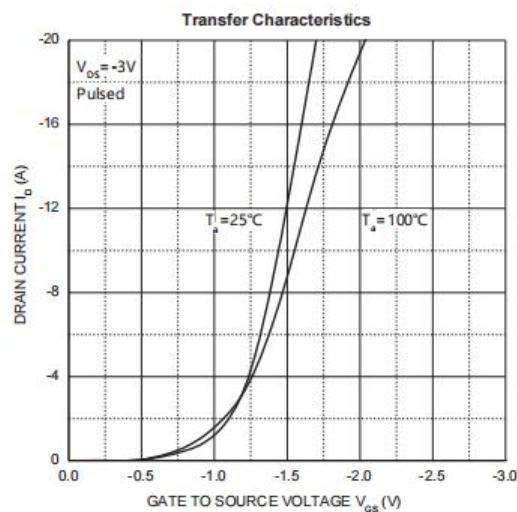
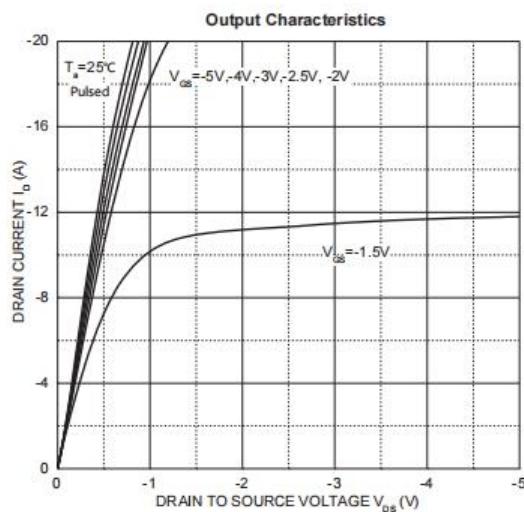
**MOSFET ELECTRICAL CHARACTERISTICS( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$	-12			V
Zero gate voltage drain current	$I_{\text{DSS}}$	$V_{\text{DS}} = -12\text{V}, V_{\text{GS}} = 0\text{V}$			-1	$\mu\text{A}$
Gate-body leakage current	$I_{\text{GSS}}$	$V_{\text{GS}} = \pm 8\text{V}, V_{\text{DS}} = 0\text{V}$			$\pm 0.1$	$\mu\text{A}$
<b>On Characteristics</b>						
Gate threshold voltage <sup>(3)</sup>	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = -250\mu\text{A}$	-0.4	-0.65	-1	V
Drain-source on-resistance <sup>(3)</sup>	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -4.5\text{V}, I_D = -5\text{A}$		19	28	$\text{m}\Omega$
		$V_{\text{GS}} = -3.7\text{V}, I_D = -4.6\text{A}$		21	32	
		$V_{\text{GS}} = -2.5\text{V}, I_D = -4.3\text{A}$		27	37	
		$V_{\text{GS}} = -1.8\text{V}, I_D = -1\text{A}$		35	63	
		$V_{\text{GS}} = -1.5\text{V}, I_D = -0.5\text{A}$		50	150	
Forward transconductance <sup>(3)</sup>	$g_{\text{FS}}$	$V_{\text{DS}} = -5\text{V}, I_D = -5\text{A}$	10	14		S
<b>Dynamic characteristics</b>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}} = -6\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		1275		$\text{pF}$
Output Capacitance	$C_{\text{oss}}$			255		
Reverse Transfer Capacitance	$C_{\text{rss}}$			236		
<b>Switching characteristics</b>						
Gate resistance	$R_g$	$f = 1\text{MHz}$	1.9		19	$\Omega$
Total gate charge	$Q_g$	$V_{\text{DS}} = -6\text{V}, V_{\text{GS}} = -4.5\text{V}, I_D = -5\text{A}$		14	21	$\text{nC}$
Gate-source charge	$Q_{\text{gs}}$			2.3		
Gate-drain charge	$Q_{\text{gd}}$			3.6		
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -6\text{V}, V_{\text{GS}} = -4.5\text{V}, I_D = -4\text{A}, R_L = 6\Omega, R_G = 1\Omega$		26		$\text{ns}$
Turn-on rise time	$t_r$			24		
Turn-off delay time	$t_{\text{d}(\text{off})}$			45		
Turn-off fall time	$t_f$			20		
<b>Source-Drain Diode characteristics</b>						
Diode forward current	$I_s$	$T_c = 25^\circ\text{C}$			-6	A
Diode pulsed forward current	$I_{\text{SM}}$				-20	A
Diode Forward voltage <sup>(3)</sup>	$V_{\text{DS}}$	$I_s = -4\text{A}, V_{\text{GS}} = 0\text{V}$			-1.2	V
Diode reverse recovery time	$t_{\text{rr}}$	$I_F = -4\text{A}, dI/dt = 100\text{A}/\mu\text{s}$		24	48	nC
Diode reverse recovery charge	$Q_{\text{rr}}$			8	16	ns

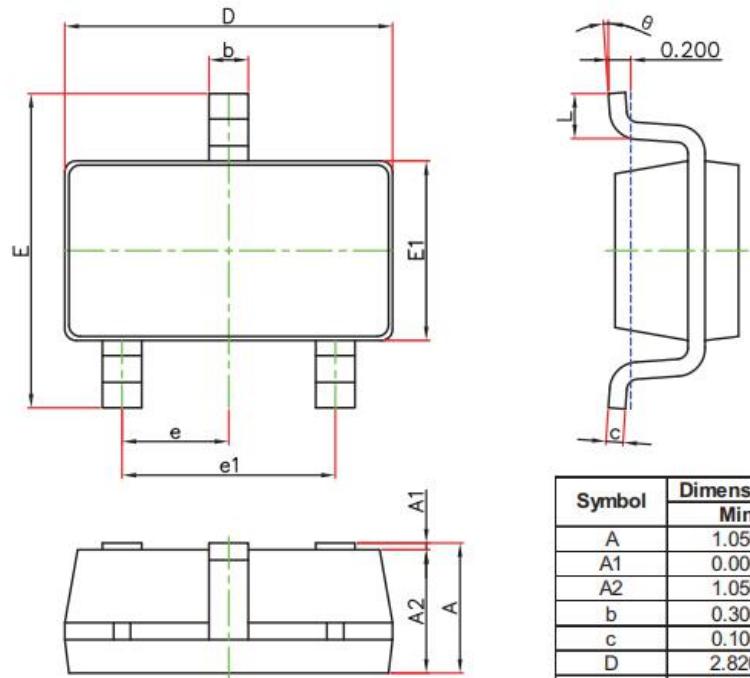
**Notes:**

- 1.The maximum current rating is limited by package.
- 2.Pulse Test : Pulse Width  $\leq 10\mu\text{s}$ , duty cycle  $\leq 1\%$ .
- 3.Pulse Test : Pulse Width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- 4.The power dissipation PD is limited by  $T_j(\text{MAX}) = 150^\circ\text{C}$ .
- 5.Device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with  $T_A = 25^\circ\text{C}$ .

## Typical Electrical and Thermal Characteristics



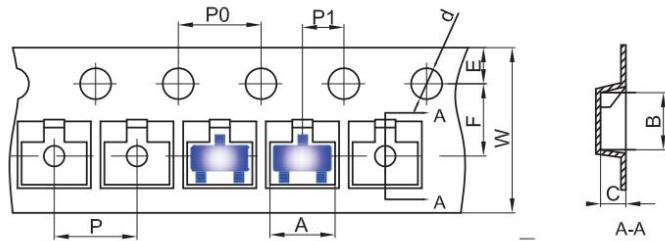
SOT-23-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

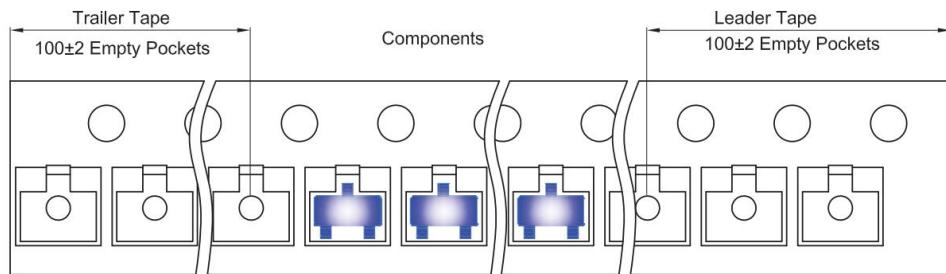
## SOT-23-3L Tape and Reel

### SOT-23-3L Embossed Carrier Tape

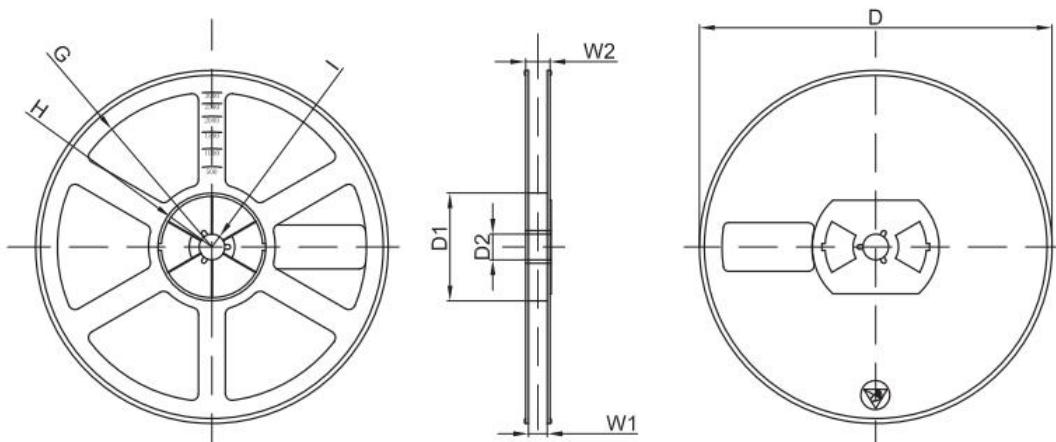


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23-3L	3.18	3.28	1.32	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

### SOT-23-3L Tape Leader and Trailer



### SOT-23-3L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	